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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	-
Number of Logic Elements/Cells	-
Total RAM Bits	36864
Number of I/O	68
Number of Gates	250000
Voltage - Supply	1.425V ~ 1.575V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 125°C (TA)
Package / Case	100-TQFP
Supplier Device Package	100-VQFP (14x14)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a3p250-vq100t

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1 – Automotive ProASIC3 Device Family Overview

General Description

Automotive ProASIC3 nonvolatile flash technology gives automotive system designers the advantage of a secure, low-power, single-chip solution that is Instant On. Automotive ProASIC3 is reprogrammable and offers time-to-market benefits at an ASIC-level unit cost. These features enable designers to create high-density systems using existing ASIC or FPGA design flows and tools.

Automotive ProASIC3 devices offer 1 kbit of on-chip, reprogrammable, nonvolatile FlashROM storage as well as clock conditioning circuitry based on an integrated phase-locked loop (PLL). Automotive ProASIC3 devices have up to 1 million system gates, supported with up to 144 kbits of SRAM and up to 300 user I/Os.

Automotive ProASIC3 devices are the only firm-error-immune automotive grade FPGAs. Firm-error immunity makes them ideally suited for demanding applications in powertrain, safety, and telematics-based subsystems, where firm-error failure is not an option.

Firm errors in SRAM-based FPGAs can result in high defect levels in field-deployed systems. These unavoidable defects must be considered separately from standard defects and failure mechanisms when looking at overall system quality and reliability.

Flash Advantages

Reduced Cost of Ownership

Advantages to the designer extend beyond low unit cost, performance, and ease of use. Unlike SRAM-based FPGAs, flash-based Automotive ProASIC3 devices allow all functionality to be Instant On; no external boot PROM is required. On-board security mechanisms prevent access to all the programming information and enable secure remote updates of the FPGA logic. Flash-based FPGAs are LAPU Class 0 devices, offering the lowest available power in a single-chip device and providing firm-error immunity. The Automotive ProASIC3 family device architecture mitigates the need for ASIC migration at high user volumes. This makes the Automotive ProASIC3 family a cost-effective ASIC replacement solution, especially for automotive applications.

Security

Nonvolatile, flash-based Automotive ProASIC3 devices do not require a boot PROM, so there is no vulnerable external bitstream that can be easily copied. Automotive ProASIC3 devices incorporate FlashLock, which provides a unique combination of reprogrammability and design security without external overhead, advantages that only an FPGA with nonvolatile flash programming can offer.

Automotive ProASIC3 devices utilize a 128-bit flash-based lock and a separate AES key to provide the highest level of protection in the FPGA industry for intellectual property and configuration data. In addition, all FlashROM data in Automotive ProASIC3 devices can be encrypted prior to loading, using the industry-leading AES-128 (FIPS192) bit block cipher encryption standard. The AES was adopted by the National Institute of Standards and Technology (NIST) in 2000 and replaces the 1977 DES standard. Automotive ProASIC3 devices have a built-in AES decryption engine and a flash-based AES key that make them the most comprehensive programmable logic device security solution available today. Automotive ProASIC3 devices with AES-based security provide a high level of protection for secure, remote field updates over public networks such as the Internet, and are designed to ensure that valuable IP remains out of the hands of system overbuilders, system cloners, and IP thieves. Additionally, security features of Automotive ProASIC3 devices provide anti-tampering protection.

Security, built into the FPGA fabric, is an inherent component of the Automotive ProASIC3 family. The flash cells are located beneath seven metal layers, and many device design and layout techniques have been used to make invasive attacks extremely difficult. The Automotive ProASIC3 family, with FlashLock and AES security, is unique in being highly resistant to both invasive and noninvasive attacks. Your valuable IP is protected with industry-standard security, making remote ISP possible. An Automotive ProASIC3 device provides the best available security for programmable logic designs.

Table 2-8 • Summary of I/O Input Buffer Power (per pin) – Default I/O Software Settings¹
Applicable to Standard Plus I/O Banks

	VMV (V)	Static Power PDC2 (mW) ¹	Dynamic Power PAC9 (μW/MHz) ²
Single-Ended			
3.3 V LVTTTL / 3.3 V LVCMOS	3.3	–	16.72
2.5 V LVCMOS	2.5	–	5.14
1.8 V LVCMOS	1.8	–	2.13
1.5 V LVCMOS (JESD8-11)	1.5	–	1.48
3.3 V PCI	3.3	–	18.13
3.3 V PCI-X	3.3	–	18.13

Notes:

1. P_{DC2} is the static power (where applicable) measured on VMV.
2. P_{AC9} is the total dynamic power measured on V_{CC} and VMV.

Table 2-9 • Summary of I/O Output Buffer Power (per pin) – Default I/O Software Settings¹
Applicable to Advanced I/O Banks

	C_{LOAD} (pF)	VCCI (V)	Static Power PDC3 (mW) ²	Dynamic Power PAC10 (μW/MHz) ³
Single-Ended				
3.3 V LVTTTL / 3.3 V LVCMOS	35	3.3	–	468.67
2.5 V LVCMOS	35	2.5	–	267.48
1.8 V LVCMOS	35	1.8	–	149.46
1.5 V LVCMOS (JESD8-11)	35	1.5	–	103.12
3.3 V PCI	10	3.3	–	201.02
3.3 V PCI-X	10	3.3	–	201.02
Differential				
LVDS	–	2.5	7.74	88.92
LVPECL	–	3.3	19.54	166.52

Notes:

1. Dynamic power consumption is given for standard load and software default drive strength and output slew.
2. P_{DC3} is the static power (where applicable) measured on VMV.
3. P_{AC10} is the total dynamic power measured on V_{CCI} and VMV.

Power Consumption of Various Internal Resources

Table 2-11 • Different Components Contributing to Dynamic Power Consumption in ProASIC3 Devices

Parameter	Definition	Device Specific Dynamic Power (μW/MHz)			
		A3P1000	A3P250	A3P125	A3P060
PAC1	Clock contribution of a Global Rib	14.50	11.00	11.00	9.30
PAC2	Clock contribution of a Global Spine	2.48	1.58	0.81	0.81
PAC3	Clock contribution of a VersaTile row	0.81			
PAC4	Clock contribution of a VersaTile used as a sequential module	0.12			
PAC5	First contribution of a VersaTile used as a sequential module	0.07			
PAC6	Second contribution of a VersaTile used as a sequential module	0.29			
PAC7	Contribution of a VersaTile used as a combinatorial module	0.29			
PAC8	Average contribution of a routing net	0.70			
PAC9	Contribution of an I/O input pin (standard-dependent)	See Table 2-7 on page 2-6 .			
PAC10	Contribution of an I/O output pin (standard-dependent)	See Table 2-7 and Table 2-10 on page 2-8 .			
PAC11	Average contribution of a RAM block during a read operation	25.00			
PAC12	Average contribution of a RAM block during a write operation	30.00			
PAC13	Static PLL contribution	2.55 mW			
PAC14	Dynamic contribution for PLL	2.60			

Note: *For a different output load, drive strength, or slew rate, Microsemi recommends using the Microsemi power spreadsheet calculator or SmartPower tool in Libero SoC.

Power Calculation Methodology

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in Libero SoC software.

The power calculation methodology described below uses the following variables:

- The number of PLLs as well as the number and the frequency of each output clock generated
- The number of combinatorial and sequential cells used in the design
- The internal clock frequencies
- The number and the standard of I/O pins used in the design
- The number of RAM blocks used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in [Table 2-12 on page 2-11](#).
- Enable rates of output buffers—guidelines are provided for typical applications in [Table 2-13 on page 2-12](#).
- Read rate and write rate to the memory—guidelines are provided for typical applications in [Table 2-13 on page 2-12](#). The calculation should be repeated for each clock domain defined in the design.

Methodology

Total Power Consumption— P_{TOTAL}

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

P_{STAT} is the total static power consumption.

P_{DYN} is the total dynamic power consumption.

Total Static Power Consumption— P_{STAT}

$$P_{STAT} = PDC1 + N_{INPUTS} * PDC2 + N_{OUTPUTS} * PDC3$$

N_{INPUTS} is the number of I/O input buffers used in the design.

$N_{OUTPUTS}$ is the number of I/O output buffers used in the design.

Total Dynamic Power Consumption— P_{DYN}

$$P_{DYN} = P_{CLOCK} + P_{S-CELL} + P_{C-CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL}$$

Global Clock Contribution— P_{CLOCK}

$$P_{CLOCK} = (PAC1 + N_{SPINE} * PAC2 + N_{ROW} * PAC3 + N_{S-CELL} * PAC4) * F_{CLK}$$

N_{SPINE} is the number of global spines used in the user design—guidelines are provided in the "Spine Architecture" section of the Global Resources chapter in the [Automotive ProASIC3 FPGA Fabric User's Guide](#).

N_{ROW} is the number of VersaTile rows used in the design—guidelines are provided in the [Automotive ProASIC3 FPGA Fabric User's Guide](#).

F_{CLK} is the global clock signal frequency.

N_{S-CELL} is the number of VersaTiles used as sequential modules in the design.

PAC1, PAC2, PAC3, and PAC4 are device-dependent.

Sequential Cells Contribution— P_{S-CELL}

$$P_{S-CELL} = N_{S-CELL} * (PAC5 + \alpha_1 / 2 * PAC6) * F_{CLK}$$

N_{S-CELL} is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

α_1 is the toggle rate of VersaTile outputs—guidelines are provided in [Table 2-12 on page 2-11](#).

F_{CLK} is the global clock signal frequency.

Combinatorial Cells Contribution— P_{C-CELL}

$$P_{C-CELL} = N_{C-CELL} * \alpha_1 / 2 * PAC7 * F_{CLK}$$

N_{C-CELL} is the number of VersaTiles used as combinatorial modules in the design.

α_1 is the toggle rate of VersaTile outputs—guidelines are provided in [Table 2-12 on page 2-11](#).

F_{CLK} is the global clock signal frequency.

Routing Net Contribution— P_{NET}

$$P_{NET} = (N_{S-CELL} + N_{C-CELL}) * \alpha_1 / 2 * PAC8 * F_{CLK}$$

N_{S-CELL} is the number VersaTiles used as sequential modules in the design.

N_{C-CELL} is the number of VersaTiles used as combinatorial modules in the design.

α_1 is the toggle rate of VersaTile outputs—guidelines are provided in [Table 2-12 on page 2-11](#).

F_{CLK} is the global clock signal frequency.

I/O Input Buffer Contribution— P_{INPUTS}

$$P_{INPUTS} = N_{INPUTS} * \alpha_2 / 2 * PAC9 * F_{CLK}$$

N_{INPUTS} is the number of I/O input buffers used in the design.

α_2 is the I/O buffer toggle rate—guidelines are provided in [Table 2-12 on page 2-11](#).

F_{CLK} is the global clock signal frequency.

Overview of I/O Performance

Summary of I/O DC Input and Output Levels – Default I/O Software Settings

Table 2-14 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions—Software Default Settings
Applicable to Advanced I/O Banks

I/O Standard	Drive Strength	Slew Rate	VIL		VIH		VOL	VOH	I _{OL}	I _{OH}
			Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTTL / 3.3 V LVCMOS	12 mA	High	−0.3	0.8	2	3.6	0.4	2.4	12	12
2.5 V LVCMOS	12 mA	High	−0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVCMOS	12 mA	High	−0.3	0.35 * V _{CCI}	0.65 * V _{CCI}	3.6	0.45	V _{CCI} − 0.45	12	12
1.5 V LVCMOS	12 mA	High	−0.3	0.30 * V _{CCI}	0.7 * V _{CCI}	3.6	0.25 * V _{CCI}	0.75 * V _{CCI}	12	12
3.3 V PCI	Per PCI specifications									
3.3 V PCI-X	Per PCI-X specifications									

Note: Currents are measured at 125°C junction temperature.

Table 2-15 • Summary of Maximum and Minimum DC Input and Output Levels Applicable to Commercial and Industrial Conditions—Software Default Settings
Applicable to Standard Plus I/O Banks

I/O Standard	Drive Strength	Slew Rate	VIL		VIH		VOL	VOH	I _{OL}	I _{OH}
			Min. V	Max. V	Min. V	Max. V	Max. V	Min. V	mA	mA
3.3 V LVTTTL / 3.3 V LVCMOS	12 mA	High	−0.3	0.8	2	3.6	0.4	2.4	12	12
2.5 V LVCMOS	12 mA	High	−0.3	0.7	1.7	3.6	0.7	1.7	12	12
1.8 V LVCMOS	8 mA	High	−0.3	0.35 * V _{CCI}	0.65 * V _{CCI}	3.6	0.45	V _{CCI} − 0.45	8	8
1.5 V LVCMOS	4 mA	High	−0.3	0.30 * V _{CCI}	0.7 * V _{CCI}	3.6	0.25 * V _{CCI}	0.75 * V _{CCI}	4	4
3.3 V PCI	Per PCI specifications									
3.3 V PCI-X	Per PCI-X specifications									

Note: Currents are measured at 125°C junction temperature.

Table 2-23 • Summary of I/O Timing Characteristics—Software Default Settings
–1 Speed Grade, Automotive-Case Conditions: $T_J = 115^{\circ}\text{C}$, Worst Case $V_{CC} = 1.425\text{ V}$
Worst Case $V_{CCI} = 3.0\text{ V}$
Standard Plus I/O Banks

I/O Standard	Drive Strength (mA)	Slew Rate	Capacitive Load (pF)	External Resistor	t_{BOUT} (ns)	t_{DP} (ns)	t_{DIN} (ns)	t_{PY} (ns)	t_{EOUT} (ns)	t_{ZL} (ns)	t_{ZH} (ns)	t_{LZ} (ns)	t_{HZ} (ns)	t_{ZLS} (ns)	t_{ZHS} (ns)	Units
3.3 V LVTTTL / 3.3 V LVCMOS	12 mA	High	35 pF	–	0.55	3.36	0.04	0.97	0.39	3.42	1.56	3.05	1.94	5.55	2.80	ns
2.5 V LVCMOS	12 mA	High	35 pF	–	0.55	3.05	0.04	1.23	0.39	3.11	2.99	1.56	1.69	5.23	5.11	ns
1.8 V LVCMOS	8 mA	High	35 pF	–	0.55	3.73	0.04	1.16	0.39	3.65	3.86	1.62	1.68	5.78	5.99	ns
1.5 V LVCMOS	4 mA	High	35 pF	–	0.55	4.60	0.04	1.35	0.39	4.61	5.05	2.07	1.85	6.74	7.18	ns
3.3 V PCI	Per PCI spec	High	10 pF	25 ²	0.55	2.55	0.04	0.82	0.39	1.27	0.94	2.65	3.06	2.49	2.18	ns
3.3 V PCI-X	Per PCI-X spec	High	10 pF	25 ²	0.55	2.55	0.04	0.79	0.39	1.27	0.94	2.65	3.06	2.49	2.18	ns

Notes:

1. For specific junction temperature and voltage supply levels, refer to [Table 2-5 on page 2-5](#) for derating values.
2. Resistance is used to measure I/O propagation delays as defined in PCI specifications. See [Figure 2-11 on page 2-48](#) for connectivity. This resistor is not required during normal operation.

Table 2-60 • 1.8 V LVCMOS Low Slew

Automotive-Case Conditions: $T_J = 135^{\circ}\text{C}$, Worst-Case $V_{CC} = 1.425\text{ V}$, Worst-Case $V_{CCI} = 2.3\text{ V}$
Applicable to Standard Plus I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.64	17.36	0.05	1.45	0.46	15.09	16.55	1.24	0.79	17.59	19.052	ns
	-1	0.55	14.77	0.04	1.23	0.39	12.84	14.08	1.24	0.79	14.96	16.207	ns
4 mA	STD	0.64	11.71	0.05	1.45	0.46	10.88	11.07	1.47	1.35	13.38	13.567	ns
	-1	0.55	9.96	0.04	1.23	0.39	9.26	9.41	1.47	1.35	11.38	11.541	ns
6 mA	STD	0.64	9.00	0.05	1.45	0.46	8.47	8.18	1.62	1.62	10.97	10.685	ns
	-1	0.55	7.66	0.04	1.23	0.39	7.21	6.96	1.62	1.62	9.33	9.089	ns
8 mA	STD	0.64	8.39	0.05	1.45	0.46	8.47	8.18	1.62	1.62	10.97	10.685	ns
	-1	0.55	7.14	0.04	1.23	0.39	7.21	6.96	1.62	1.62	9.33	9.089	ns

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-5 on page 2-5](#) for derating values.

Table 2-61 • 1.8 V LVCMOS High Slew

Automotive-Case Conditions: $T_J = 115^{\circ}\text{C}$, Worst-Case $V_{CC} = 1.425\text{ V}$, Worst-Case $V_{CCI} = 2.3\text{ V}$
Applicable to Advanced I/O Banks

Drive Strength	Speed Grade	t_{DOUT}	t_{DP}	t_{DIN}	t_{PY}	t_{EOUT}	t_{ZL}	t_{ZH}	t_{LZ}	t_{HZ}	t_{ZLS}	t_{ZHS}	Units
2 mA	STD	0.63	12.83	0.05	1.32	0.45	9.88	12.83	1.48	0.87	12.30	15.25	ns
	-1	0.53	10.92	0.04	1.12	0.38	8.41	10.92	1.48	0.87	10.46	12.97	ns
4 mA	STD	0.63	7.48	0.05	1.32	0.45	6.34	7.48	1.72	1.49	8.76	9.90	ns
	-1	0.53	6.36	0.04	1.12	0.38	5.39	6.36	1.72	1.49	7.45	8.42	ns
6 mA	STD	0.63	4.81	0.05	1.32	0.45	4.52	4.81	1.89	1.77	6.94	7.23	ns
	-1	0.53	4.09	0.04	1.12	0.38	3.85	4.09	1.89	1.77	5.90	6.15	ns
8 mA	STD	0.63	4.25	0.05	1.32	0.45	4.25	4.25	1.92	1.85	6.67	6.66	ns
	-1	0.53	3.61	0.04	1.12	0.38	3.61	3.61	1.93	1.85	5.67	5.67	ns
12 mA	STD	0.63	3.82	0.05	1.32	0.45	1.89	1.63	4.00	4.41	3.06	2.82	ns
	-1	0.53	3.25	0.04	1.12	0.38	1.89	1.63	3.41	3.75	3.06	2.82	ns
16 mA	STD	0.63	3.82	0.05	1.32	0.45	1.89	1.63	4.00	4.41	3.06	2.82	ns
	-1	0.53	3.25	0.04	1.12	0.38	1.89	1.63	3.41	3.75	3.06	2.82	ns

Notes:

1. Software default selection highlighted in gray.
2. For specific junction temperature and voltage supply levels, refer to [Table 2-5 on page 2-5](#) for derating values.

Table 2-95 • Output Data Register Propagation Delays
Automotive-Case Conditions: $T_J = 115^\circ\text{C}$, Worst-Case $V_{CC} = 1.425\text{ V}$

Parameter	Description	–1	Std.	Units
t_{OCLKQ}	Clock-to-Q of the Output Data Register	0.70	0.82	ns
t_{OSUD}	Data Setup Time for the Output Data Register	0.37	0.44	ns
t_{OHD}	Data Hold Time for the Output Data Register	0.00	0.00	ns
t_{OSUE}	Enable Setup Time for the Output Data Register	0.52	0.61	ns
t_{OHE}	Enable Hold Time for the Output Data Register	0.00	0.00	ns
t_{OCLR2Q}	Asynchronous Clear-to-Q of the Output Data Register	0.96	1.12	ns
t_{OPRE2Q}	Asynchronous Preset-to-Q of the Output Data Register	0.96	1.12	ns
t_{OREMCLR}	Asynchronous Clear Removal Time for the Output Data Register	0.00	0.00	ns
t_{ORECCLR}	Asynchronous Clear Recovery Time for the Output Data Register	0.27	0.31	ns
t_{OREMPRE}	Asynchronous Preset Removal Time for the Output Data Register	0.00	0.00	ns
t_{ORECPRE}	Asynchronous Preset Recovery Time for the Output Data Register	0.27	0.31	ns
t_{OWCLR}	Asynchronous Clear Minimum Pulse Width for the Output Data Register	0.25	0.30	ns
t_{OWPRE}	Asynchronous Preset Minimum Pulse Width for the Output Data Register	0.25	0.30	ns
t_{OCKMPWH}	Clock Minimum Pulse Width High for the Output Data Register	0.41	0.48	ns
t_{OCKMPWL}	Clock Minimum Pulse Width Low for the Output Data Register	0.37	0.43	ns

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-5 on page 2-5](#) for derating values.

Timing Characteristics

Table 2-104 • Combinatorial Cell Propagation Delays
Automotive-Case Conditions: $T_J = 135^{\circ}\text{C}$, Worst-Case $V_{CC} = 1.425\text{ V}$

Combinatorial Cell	Equation	Parameter	-1	Std.	Units
INV	$Y = !A$	t_{PD}	0.49	0.57	ns
AND2	$Y = A \cdot B$	t_{PD}	0.57	0.67	ns
NAND2	$Y = !(A \cdot B)$	t_{PD}	0.57	0.67	ns
OR2	$Y = A + B$	t_{PD}	0.59	0.69	ns
NOR2	$Y = !(A + B)$	t_{PD}	0.59	0.69	ns
XOR2	$Y = A \oplus B$	t_{PD}	0.90	1.05	ns
MAJ3	$Y = \text{MAJ}(A, B, C)$	t_{PD}	0.85	1.00	ns
XOR3	$Y = A \oplus B \oplus C$	t_{PD}	1.06	1.25	ns
MUX2	$Y = A !S + B S$	t_{PD}	0.62	0.72	ns
AND3	$Y = A \cdot B \cdot C$	t_{PD}	0.68	0.80	ns

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-5 on page 2-5](#) for derating values.

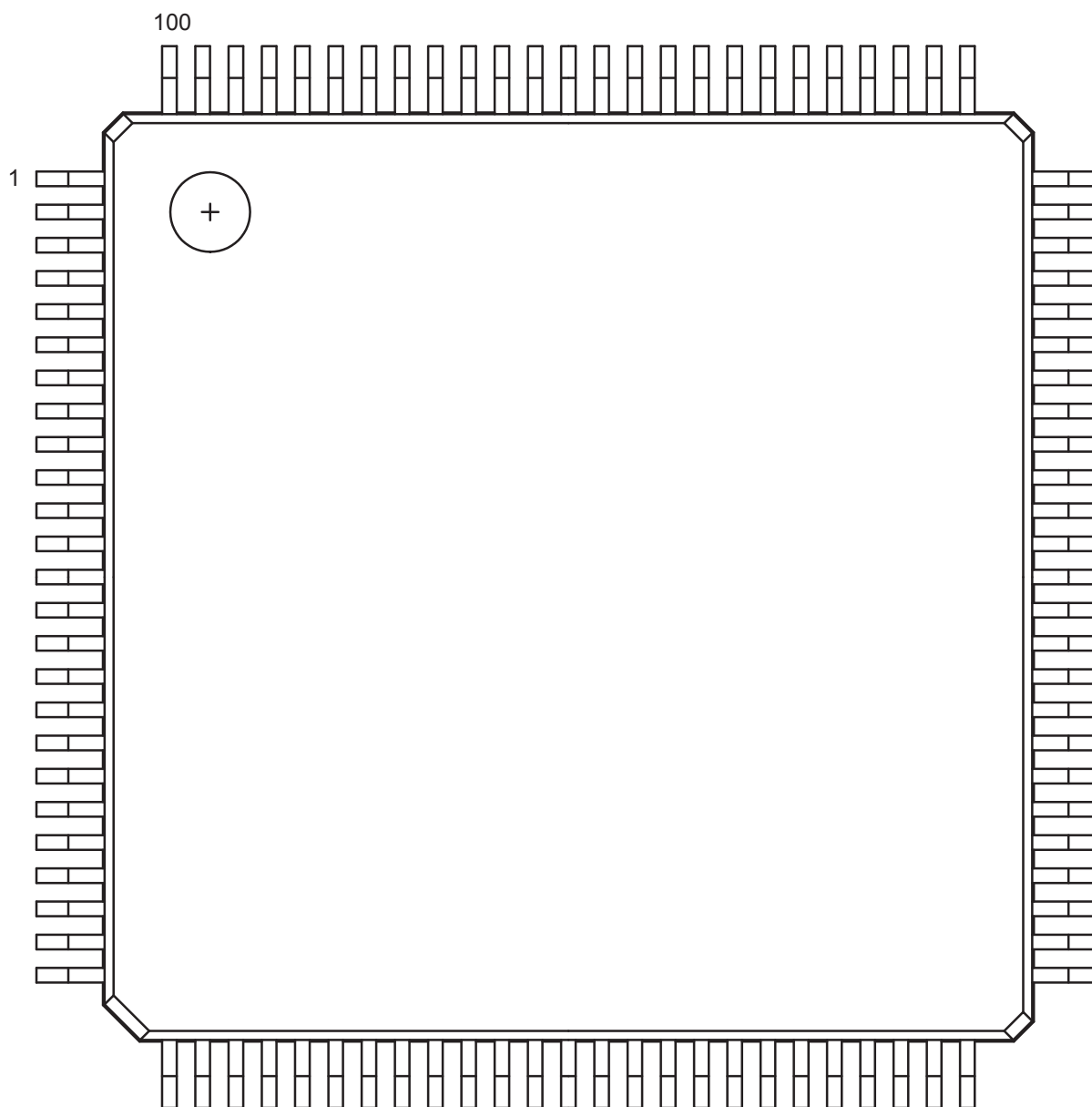
Table 2-105 • Combinatorial Cell Propagation Delays
Automotive-Case Conditions: $T_J = 115^{\circ}\text{C}$, Worst-Case $V_{CC} = 1.425\text{ V}$

Combinatorial Cell	Equation	Parameter	-1	Std.	Units
INV	$Y = !A$	t_{PD}	0.48	0.56	ns
AND2	$Y = A \cdot B$	t_{PD}	0.56	0.66	ns
NAND2	$Y = !(A \cdot B)$	t_{PD}	0.56	0.66	ns
OR2	$Y = A + B$	t_{PD}	0.58	0.68	ns
NOR2	$Y = !(A + B)$	t_{PD}	0.58	0.68	ns
XOR2	$Y = A \oplus B$	t_{PD}	0.88	1.03	ns
MAJ3	$Y = \text{MAJ}(A, B, C)$	t_{PD}	0.83	0.98	ns
XOR3	$Y = A \oplus B \oplus C$	t_{PD}	1.04	1.23	ns
MUX2	$Y = A !S + B S$	t_{PD}	0.60	0.71	ns
AND3	$Y = A \cdot B \cdot C$	t_{PD}	0.67	0.79	ns

Note: For specific junction temperature and voltage supply levels, refer to [Table 2-5 on page 2-5](#) for derating values.

4 – Package Pin Assignments

VQ100



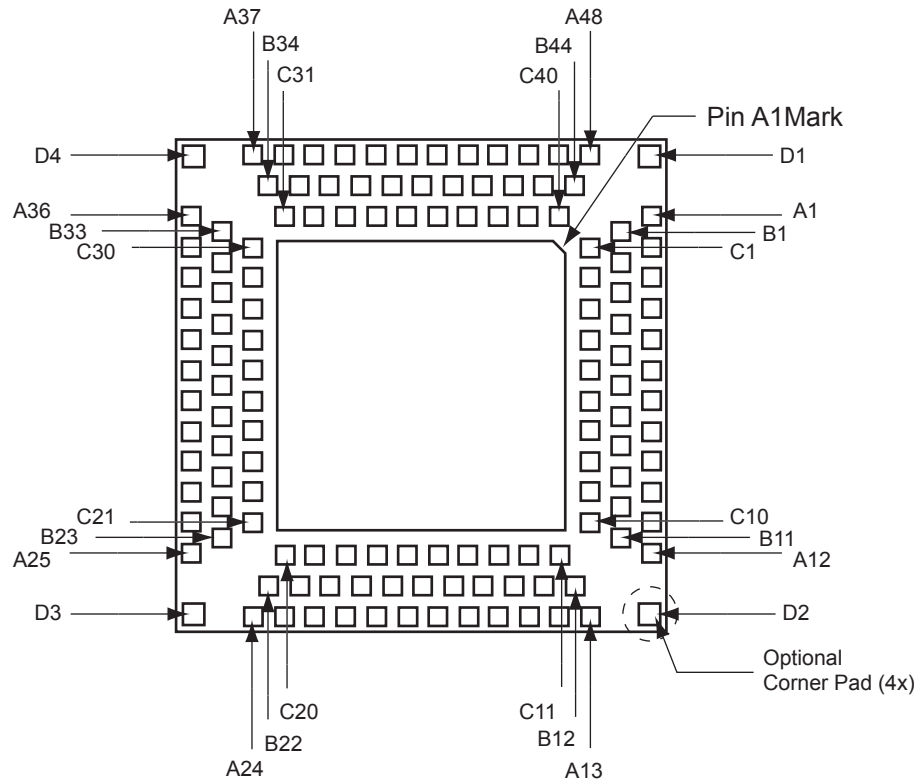
Note: This is the top view of the package.

Note

For Package Manufacturing and Environmental information, visit the Resource Center at <http://www.actel.com/products/solutions/package/docs.aspx>.

VQ100		VQ100		VQ100	
Pin Number	A3P250 Function	Pin Number	A3P250 Function	Pin Number	A3P250 Function
1	GND	35	IO85RSB2	69	IO43NDB1
2	GAA2/IO118UDB3	36	IO84RSB2	70	GBC2/IO43PDB1
3	IO118VDB3	37	VCC	71	GBB2/IO42PSB1
4	GAB2/IO117UDB3	38	GND	72	IO41NDB1
5	IO117VDB3	39	VCCIB2	73	GBA2/IO41PDB1
6	GAC2/IO116UDB3	40	IO77RSB2	74	VMV1
7	IO116VDB3	41	IO74RSB2	75	GNDQ
8	IO112PSB3	42	IO71RSB2	76	GBA1/IO40RSB0
9	GND	43	GDC2/IO63RSB2	77	GBA0/IO39RSB0
10	GFB1/IO109PDB3	44	GDB2/IO62RSB2	78	GBB1/IO38RSB0
11	GFB0/IO109NDB3	45	GDA2/IO61RSB2	79	GBB0/IO37RSB0
12	VCOMPLF	46	GNDQ	80	GBC1/IO36RSB0
13	GFA0/IO108NPB3	47	TCK	81	GBC0/IO35RSB0
14	VCCPLF	48	TDI	82	IO29RSB0
15	GFA1/IO108PPB3	49	TMS	83	IO27RSB0
16	GFA2/IO107PSB3	50	VMV2	84	IO25RSB0
17	VCC	51	GND	85	IO23RSB0
18	VCCIB3	52	VPUMP	86	IO21RSB0
19	GFC2/IO105PSB3	53	NC	87	VCCIB0
20	GEC1/IO100PDB3	54	TDO	88	GND
21	GEC0/IO100NDB3	55	TRST	89	VCC
22	GEA1/IO98PDB3	56	VJTAG	90	IO15RSB0
23	GEA0/IO98NDB3	57	GDA1/IO60USB1	91	IO13RSB0
24	VMV3	58	GDC0/IO58VDB1	92	IO11RSB0
25	GNDQ	59	GDC1/IO58UDB1	93	GAC1/IO05RSB0
26	GEA2/IO97RSB2	60	IO52NDB1	94	GAC0/IO04RSB0
27	GEB2/IO96RSB2	61	GCB2/IO52PDB1	95	GAB1/IO03RSB0
28	GEC2/IO95RSB2	62	GCA1/IO50PDB1	96	GAB0/IO02RSB0
29	IO93RSB2	63	GCA0/IO50NDB1	97	GAA1/IO01RSB0
30	IO92RSB2	64	GCC0/IO48NDB1	98	GAA0/IO00RSB0
31	IO91RSB2	65	GCC1/IO48PDB1	99	GNDQ
32	IO90RSB2	66	VCCIB1	100	VMV0
33	IO88RSB2	67	GND		
34	IO86RSB2	68	VCC		

QN132



Notes:

1. This is the bottom view of the package.
2. The die attach paddle center of the package is tied to ground (GND).

Note

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QN132	
Pin Number	A3P250 Function
A1	GAB2/IO117UPB3
A2	IO117VPB3
A3	VCCIB3
A4	GFC1/IO110PDB3
A5	GFB0/IO109NPB3
A6	VCCPLF
A7	GFA1/IO108PPB3
A8	GFC2/IO105PPB3
A9	IO103NDB3
A10	VCC
A11	GEA1/IO98PPB3
A12	GEA0/IO98NPB3
A13	GEC2/IO95RSB2
A14	IO91RSB2
A15	VCC
A16	IO90RSB2
A17	IO87RSB2
A18	IO85RSB2
A19	IO82RSB2
A20	IO76RSB2
A21	IO70RSB2
A22	VCC
A23	GDB2/IO62RSB2
A24	TDI
A25	TRST
A26	GDC1/IO58UDB1
A27	VCC
A28	IO54NDB1
A29	IO52NDB1
A30	GCA2/IO51PPB1
A31	GCA0/IO50NPB1
A32	GCB1/IO49PDB1
A33	IO47NSB1
A34	VCC
A35	IO41NPB1
A36	GBA2/IO41PPB1

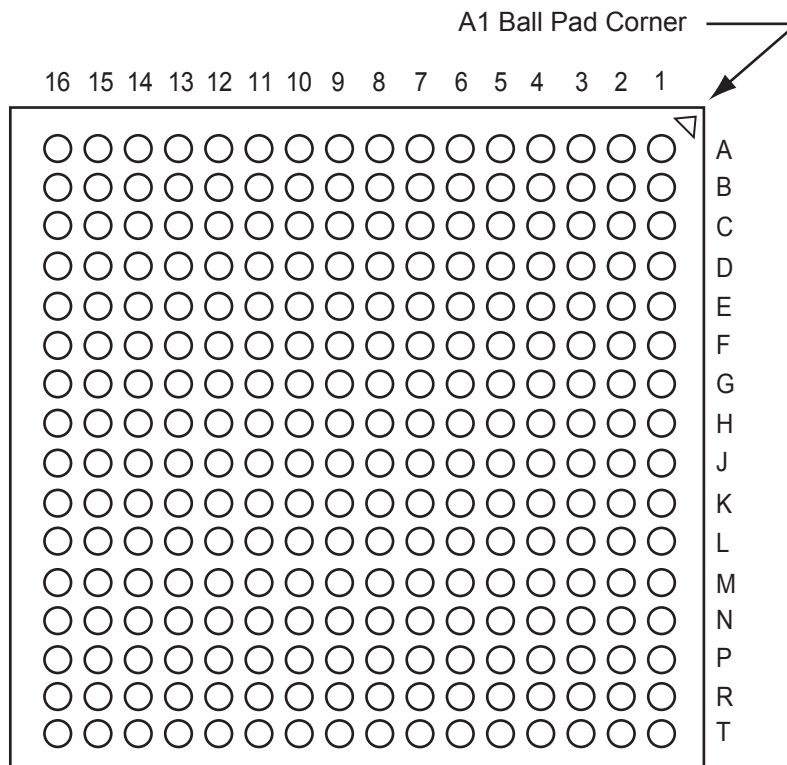
QN132	
Pin Number	A3P250 Function
A37	GBB1/IO38RSB0
A38	GBC0/IO35RSB0
A39	VCCIB0
A40	IO28RSB0
A41	IO22RSB0
A42	IO18RSB0
A43	IO14RSB0
A44	IO11RSB0
A45	IO07RSB0
A46	VCC
A47	GAC1/IO05RSB0
A48	GAB0/IO02RSB0
B1	IO118VDB3
B2	GAC2/IO116UDB3
B3	GND
B4	GFC0/IO110NDB3
B5	VCOMPLF
B6	GND
B7	GFB2/IO106PSB3
B8	IO103PDB3
B9	GND
B10	GEB0/IO99NDB3
B11	VMV3
B12	GEB2/IO96RSB2
B13	IO92RSB2
B14	GND
B15	IO89RSB2
B16	IO86RSB2
B17	GND
B18	IO78RSB2
B19	IO72RSB2
B20	GND
B21	GNDQ
B22	TMS
B23	TDO
B24	GDC0/IO58VDB1

QN132	
Pin Number	A3P250 Function
B25	GND
B26	IO54PDB1
B27	GCB2/IO52PDB1
B28	GND
B29	GCB0/IO49NDB1
B30	GCC1/IO48PDB1
B31	GND
B32	GBB2/IO42PDB1
B33	VMV1
B34	GBA0/IO39RSB0
B35	GBC1/IO36RSB0
B36	GND
B37	IO26RSB0
B38	IO21RSB0
B39	GND
B40	IO13RSB0
B41	IO08RSB0
B42	GND
B43	GAC0/IO04RSB0
B44	GNDQ
C1	GAA2/IO118UDB3
C2	IO116VDB3
C3	VCC
C4	GFB1/IO109PPB3
C5	GFA0/IO108NPB3
C6	GFA2/IO107PSB3
C7	IO105NPB3
C8	VCCIB3
C9	GEB1/IO99PDB3
C10	GNDQ
C11	GEA2/IO97RSB2
C12	IO94RSB2
C13	VCCIB2
C14	IO88RSB2
C15	IO84RSB2
C16	IO80RSB2

FG144		FG144		FG144	
Pin Number	A3P060 Function	Pin Number	A3P060 Function	Pin Number	A3P060 Function
A1	GNDQ	D1	IO91RSB1	G1	GFA1/IO84RSB1
A2	VMV0	D2	IO92RSB1	G2	GND
A3	GAB0/IO04RSB0	D3	IO93RSB1	G3	VCCPLF
A4	GAB1/IO05RSB0	D4	GAA2/IO51RSB1	G4	GFA0/IO85RSB1
A5	IO08RSB0	D5	GAC0/IO06RSB0	G5	GND
A6	GND	D6	GAC1/IO07RSB0	G6	GND
A7	IO11RSB0	D7	GBC0/IO19RSB0	G7	GND
A8	VCC	D8	GBC1/IO20RSB0	G8	GDC1/IO45RSB0
A9	IO16RSB0	D9	GBB2/IO27RSB0	G9	IO32RSB0
A10	GBA0/IO23RSB0	D10	IO18RSB0	G10	GCC2/IO43RSB0
A11	GBA1/IO24RSB0	D11	IO28RSB0	G11	IO31RSB0
A12	GNDQ	D12	GCB1/IO37RSB0	G12	GCB2/IO42RSB0
B1	GAB2/IO53RSB1	E1	VCC	H1	VCC
B2	GND	E2	GFC0/IO88RSB1	H2	GFB2/IO82RSB1
B3	GAA0/IO02RSB0	E3	GFC1/IO89RSB1	H3	GFC2/IO81RSB1
B4	GAA1/IO03RSB0	E4	VCCIB1	H4	GEC1/IO77RSB1
B5	IO00RSB0	E5	IO52RSB1	H5	VCC
B6	IO10RSB0	E6	VCCIB0	H6	IO34RSB0
B7	IO12RSB0	E7	VCCIB0	H7	IO44RSB0
B8	IO14RSB0	E8	GCC1/IO35RSB0	H8	GDB2/IO55RSB1
B9	GBB0/IO21RSB0	E9	VCCIB0	H9	GDC0/IO46RSB0
B10	GBB1/IO22RSB0	E10	VCC	H10	VCCIB0
B11	GND	E11	GCA0/IO40RSB0	H11	IO33RSB0
B12	VMV0	E12	IO30RSB0	H12	VCC
C1	IO95RSB1	F1	GFB0/IO86RSB1	J1	GEB1/IO75RSB1
C2	GFA2/IO83RSB1	F2	VCOMPLF	J2	IO78RSB1
C3	GAC2/IO94RSB1	F3	GFB1/IO87RSB1	J3	VCCIB1
C4	VCC	F4	IO90RSB1	J4	GEC0/IO76RSB1
C5	IO01RSB0	F5	GND	J5	IO79RSB1
C6	IO09RSB0	F6	GND	J6	IO80RSB1
C7	IO13RSB0	F7	GND	J7	VCC
C8	IO15RSB0	F8	GCC0/IO36RSB0	J8	TCK
C9	IO17RSB0	F9	GCB0/IO38RSB0	J9	GDA2/IO54RSB1
C10	GBA2/IO25RSB0	F10	GND	J10	TDO
C11	IO26RSB0	F11	GCA1/IO39RSB0	J11	GDA1/IO49RSB0
C12	GBC2/IO29RSB0	F12	GCA2/IO41RSB0	J12	GDB1/IO47RSB0

FG144	
Pin Number	A3P060 Function
K1	GEB0/IO74RSB1
K2	GEA1/IO73RSB1
K3	GEA0/IO72RSB1
K4	GEA2/IO71RSB1
K5	IO65RSB1
K6	IO64RSB1
K7	GND
K8	IO57RSB1
K9	GDC2/IO56RSB1
K10	GND
K11	GDA0/IO50RSB0
K12	GDB0/IO48RSB0
L1	GND
L2	VMV1
L3	GEB2/IO70RSB1
L4	IO67RSB1
L5	VCCIB1
L6	IO62RSB1
L7	IO59RSB1
L8	IO58RSB1
L9	TMS
L10	VJTAG
L11	VMV1
L12	TRST
M1	GNDQ
M2	GEC2/IO69RSB1
M3	IO68RSB1
M4	IO66RSB1
M5	IO63RSB1
M6	IO61RSB1
M7	IO60RSB1
M8	NC
M9	TDI
M10	VCCIB1
M11	VPUMP
M12	GNDQ

FG256



Note: This is the bottom view of the package.

Note

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FG484		FG484		FG484	
Pin Number	A3P1000 Function	Pin Number	A3P1000 Function	Pin Number	A3P1000 Function
K19	IO88NDB1	M11	GND	P3	IO199NDB3
K20	IO94NPB1	M12	GND	P4	IO202NDB3
K21	IO98NDB1	M13	GND	P5	IO202PDB3
K22	IO98PDB1	M14	VCC	P6	IO196PPB3
L1	NC	M15	GCB2/IO95PPB1	P7	IO193PPB3
L2	IO200PDB3	M16	GCA1/IO93PPB1	P8	VCCIB3
L3	IO210NPB3	M17	GCC2/IO96PPB1	P9	GND
L4	GFB0/IO208NPB3	M18	IO100PPB1	P10	VCC
L5	GFA0/IO207NDB3	M19	GCA2/IO94PPB1	P11	VCC
L6	GFB1/IO208PPB3	M20	IO101PPB1	P12	VCC
L7	VCOMPLF	M21	IO99PPB1	P13	VCC
L8	GFC0/IO209NPB3	M22	NC	P14	GND
L9	VCC	N1	IO201NDB3	P15	VCCIB1
L10	GND	N2	IO201PDB3	P16	GDB0/IO112NPB1
L11	GND	N3	NC	P17	IO106NDB1
L12	GND	N4	GFC2/IO204PDB3	P18	IO106PDB1
L13	GND	N5	IO204NDB3	P19	IO107PDB1
L14	VCC	N6	IO203NDB3	P20	NC
L15	GCC0/IO91NPB1	N7	IO203PDB3	P21	IO104PDB1
L16	GCB1/IO92PPB1	N8	VCCIB3	P22	IO103NDB1
L17	GCA0/IO93NPB1	N9	VCC	R1	NC
L18	IO96NPB1	N10	GND	R2	IO197PPB3
L19	GCB0/IO92NPB1	N11	GND	R3	VCC
L20	IO97PDB1	N12	GND	R4	IO197NPB3
L21	IO97NDB1	N13	GND	R5	IO196NPB3
L22	IO99NPB1	N14	VCC	R6	IO193NPB3
M1	NC	N15	VCCIB1	R7	GEC0/IO190NPB3
M2	IO200NDB3	N16	IO95NPB1	R8	VMV3
M3	IO206NDB3	N17	IO100NPB1	R9	VCCIB2
M4	GFA2/IO206PDB3	N18	IO102NDB1	R10	VCCIB2
M5	GFA1/IO207PDB3	N19	IO102PDB1	R11	IO147RSB2
M6	VCCPLF	N20	NC	R12	IO136RSB2
M7	IO205NDB3	N21	IO101NPB1	R13	VCCIB2
M8	GFB2/IO205PDB3	N22	IO103PDB1	R14	VCCIB2
M9	VCC	P1	NC	R15	VMV2
M10	GND	P2	IO199PDB3	R16	IO110NDB1

FG484	
Pin Number	A3P1000 Function
R17	GDB1/IO112PPB1
R18	GDC1/IO111PDB1
R19	IO107NDB1
R20	VCC
R21	IO104NDB1
R22	IO105PDB1
T1	IO198PDB3
T2	IO198NDB3
T3	NC
T4	IO194PPB3
T5	IO192PPB3
T6	GEC1/IO190PPB3
T7	IO192NPB3
T8	GNDQ
T9	GEA2/IO187RSB2
T10	IO161RSB2
T11	IO155RSB2
T12	IO141RSB2
T13	IO129RSB2
T14	IO124RSB2
T15	GNDQ
T16	IO110PDB1
T17	VJTAG
T18	GDC0/IO111NDB1
T19	GDA1/IO113PDB1
T20	NC
T21	IO108PDB1
T22	IO105NDB1
U1	IO195PDB3
U2	IO195NDB3
U3	IO194NPB3
U4	GEB1/IO189PDB3
U5	GEB0/IO189NDB3
U6	VMV2
U7	IO179RSB2
U8	IO171RSB2

FG484	
Pin Number	A3P1000 Function
U9	IO165RSB2
U10	IO159RSB2
U11	IO151RSB2
U12	IO137RSB2
U13	IO134RSB2
U14	IO128RSB2
U15	VMV1
U16	TCK
U17	VPUMP
U18	TRST
U19	GDA0/IO113NDB1
U20	NC
U21	IO108NDB1
U22	IO109PDB1
V1	NC
V2	NC
V3	GND
V4	GEA1/IO188PDB3
V5	GEA0/IO188NDB3
V6	IO184RSB2
V7	GEC2/IO185RSB2
V8	IO168RSB2
V9	IO163RSB2
V10	IO157RSB2
V11	IO149RSB2
V12	IO143RSB2
V13	IO138RSB2
V14	IO131RSB2
V15	IO125RSB2
V16	GDB2/IO115RSB2
V17	TDI
V18	GNDQ
V19	TDO
V20	GND
V21	NC
V22	IO109NDB1

FG484	
Pin Number	A3P1000 Function
W1	NC
W2	IO191PDB3
W3	NC
W4	GND
W5	IO183RSB2
W6	GEB2/IO186RSB2
W7	IO172RSB2
W8	IO170RSB2
W9	IO164RSB2
W10	IO158RSB2
W11	IO153RSB2
W12	IO142RSB2
W13	IO135RSB2
W14	IO130RSB2
W15	GDC2/IO116RSB2
W16	IO120RSB2
W17	GDA2/IO114RSB2
W18	TMS
W19	GND
W20	NC
W21	NC
W22	NC
Y1	VCCIB3
Y2	IO191NDB3
Y3	NC
Y4	IO182RSB2
Y5	GND
Y6	IO177RSB2
Y7	IO174RSB2
Y8	VCC
Y9	VCC
Y10	IO154RSB2
Y11	IO148RSB2
Y12	IO140RSB2
Y13	NC
Y14	VCC

FG484	
Pin Number	A3P1000 Function
Y15	VCC
Y16	NC
Y17	NC
Y18	GND
Y19	NC
Y20	NC
Y21	NC
Y22	VCCIB1
AA1	GND
AA2	VCCIB3
AA3	NC
AA4	IO181RSB2
AA5	IO178RSB2
AA6	IO175RSB2
AA7	IO169RSB2
AA8	IO166RSB2
AA9	IO160RSB2
AA10	IO152RSB2
AA11	IO146RSB2
AA12	IO139RSB2
AA13	IO133RSB2
AA14	NC
AA15	NC
AA16	IO122RSB2
AA17	IO119RSB2
AA18	IO117RSB2
AA19	NC
AA20	NC
AA21	VCCIB1
AA22	GND
AB1	GND
AB2	GND
AB3	VCCIB2
AB4	IO180RSB2
AB5	IO176RSB2
AB6	IO173RSB2

FG484	
Pin Number	A3P1000 Function
AB7	IO167RSB2
AB8	IO162RSB2
AB9	IO156RSB2
AB10	IO150RSB2
AB11	IO145RSB2
AB12	IO144RSB2
AB13	IO132RSB2
AB14	IO127RSB2
AB15	IO126RSB2
AB16	IO123RSB2
AB17	IO121RSB2
AB18	IO118RSB2
AB19	NC
AB20	VCCIB2
AB21	GND
AB22	GND